

# Tentative Product Specification - MIFFXXXCY3AQ -

32GB SDHC Memory Card 64GB SDXC Memory Card 128GB SDXC Memory Card

Document Number: F22003 (Version 1.0)

# [Overview]

- Flash Type
  - YMTC
- Bus Speed Mode
  - UHS-I, SDR104
- Speed Class
  - Class 10
  - A1

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- U1 (32GB) / U3 (64/128GB)
- V10 (32GB) / V30 (64/128GB)
- Power Consumption
  - Power Up Current < 250uA</li>
  - Standby Current < 1000uA</li>
  - Read Current < 400mA</li>
  - Write Current < 400mA</li>

- Advanced Flash Management
  - ECC Correction
  - Static and Dynamic Wear Leveling
  - Bad Block Management
- Write Protect with mechanical switch
- Supply Voltage 2.7 ~ 3.6V
- Temperature Range (Ta)
  - Operation: -25°C ~ +85°C
  - Storage: -40°C ~ +85°C
- RoHS compliant

Metorage Semiconductor Technology Co.,Ltd.

## **MIFFXXXCY3AQ**

Revision	History	Date	Author
1.0	Preliminary version	2022/08/10	Fang
	50		
			<u>.</u>

### History of Specification Change

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# 1. INTRODUCTION

#### **1.1.** General Description

The SD card is fully compliant with the standards released by the SD Card Association. The Command List supports [Part 1 Physical Layer Specification Ver6.10 Final] definitions. Card capacities of the nonsecure area and secure area (if needed) support [Part 3 Security Specification Ver7.0](Normally, it is now CPRM Card) Specifications.

The SD card comes with an 9-pin interface, designed to operate at a maximum frequency of 208MHz. It can alternate communication protocol between the SD mode and SPI mode. It performs data error detection and correction with very low power consumption. SD card are one of the most popular removable storage cards today due to its high performance, good reliability and wide compatibility.

#### 1.2. Flash Management

#### 1.2.1. Error Correction Code

Flash memory cells will deteriorate with use, which might generate random bit errors in the stored data. Thus, SD card applies ECC Algorithm, which can detect and correct errors during Read processes, ensuring data is read correctly, as well as protecting data from corruption.

#### 1.2.2. Wear Leveling

NAND Flash devices can only undergo a limited number of program/erase cycles, and in most cases, the flash media are not used evenly. If some area gets updated more frequently than others, the lifetime of the device would be reduced significantly. Thus, Wear Leveling technique is applied to extend the lifespan of NAND Flash by evenly distributing write and erase cycles across the media.

Metorage provides advanced Wear Leveling algorithm, which can efficiently spread out the flash usage through the whole flash media area. Moreover, by implementing both dynamic and static Wear Leveling algorithms, the life expectancy of the NAND Flash is greatly improved.

#### 1.2.3. Bad Block Management

Bad blocks are blocks that include one or more invalid bits, and their reliability is not guaranteed. Blocks that are identified and marked as bad by the manufacturer are referred to as "Initial Bad Blocks". Bad blocks that are developed during the lifespan of the flash are named "Later Bad Blocks". Metorage implements an efficient bad block management algorithm to detect the factory-produced bad blocks and manages any bad blocks that appear with use. This practice further prevents data being stored into bad blocks and improves the data reliability.

### 2. PRODUCT SPECIFICATIONS

- Compliant Specifications SD Memory Card Specifications:
- Compliant with Part 1 Physical Layer Specification Ver. 6.10
- Compliant with Part 2 File System Specification Ver. 3.00
- Compliant with Part 3 Security Specification Ver. 7.00
- Standard Size SD Card Mechanical Addendum Ver . 7.0
- Support SD SPI mode
  - Bus Speed Mode (use 4 parallel data lines)
  - Non-UHS Mode
    - Default speed mode: 3.3V signaling, frequency up to 25MHz, up to 12.5 MB/sec
    - High speed mode: 3.3V signaling, frequency up to 50MHz, up to 25 MB/sec
    - UHS Mode

- SDR12: 1.8V signaling, frequency up to 25MHz, up to 12.5 MB/sec
- SDR25: 1.8V signaling, frequency up to 50MHz, up to 25 MB/sec
- SDR50: 1.8V signaling, frequency up to 100MHz, up to 50 MB/sec
- SDR104: 1.8V signaling, frequency up to 208MHz, up to 104MB/sec
- DDR50: 1.8V signaling, frequency up to 50MHz, sampled on both clock edges, up to 50 MB/sec

**NOTES:** 1. Timing in 1.8V signaling is different from that of 3.3V signaling.

- 2. To properly run the UHS mode, please ensure the device supports UHS-I mode.
- The command list supports [Part 1 Physical Layer Specification Ver. 6.10 ] definitions
- Command list are described in "Table 3-2 SD mode Command Set " and "Table 3-3 SPI mode Command Set" in this document

- **Copyrights Protection Mechanism** 
  - Compliant with Part 1 Physical Layer Specification ver. 6.10, CPRM is Optional in SDHC/SDXC.
- **Support Hot Plug**
- Card removal during read operation will never harm the content
- Password Protection of cards (support)
- Designed for read intensive and write intensive cards
- Built-in write protection features (permanent and temporary)
- Write Protect feature using mechanical switch (Full SD Card only)
- Electrostatic Discharge (ESD) is checked with SDA Specification.
- ESD protection in pads (contact discharge).
  - ESD protection in non-contact pad area (air discharge).
- Operation voltage range: 2.7V ~ 3.6V
- Temperature Range (Ta)
  - Operation Temp. Range: -25°C~+85°C Storage Temp. Range: -40°C~+85°C

# 3. ELECTRICAL INTERFACE OUTLINES

#### 3.1. Pad Assignment and Descriptions

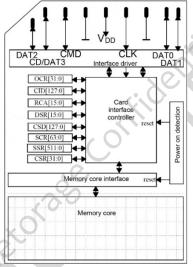


Figure 3-1 SD Memory Card Pin Assignment(Back View of the card)

Pin		SD	Mode	SPI Mode					
PIII	Name	Type <sup>1</sup>	Description	Name	Туре	Description			
1	CD/DAT3 <sup>2</sup>	I/O/PP <sup>3</sup>	Card Detect/ Data Line [bit3]	CS	I <sup>3</sup>	Chip Select (neg. true)			
2	CMD	PP	Command/Response	DI	I	Data In			
3	VSS1	S	Supply voltage ground	VSS	S	Supply voltage ground			
4	VDD	S	Supply voltage	VDD	S	Supply voltage			
5	CLK	I	Clock	SCLK	I	Clock			
6	VSS2	S	Supply voltage ground	VSS2	S	Supply voltage ground			
7	DAT0	I/O/PP	Data Line [bito]	DO	0/PP	Data Out			
8	DAT1	I/O/PP	Data Line [bit1]	RSV	-	-			
9	DAT2	I/O/PP	Data Line [bit2]	RSV	-	-			

#### Table 3-1 SD Memory Card Pad Assignment

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- (1) S: power supply, I: input; O: output using push-pull drivers; PP: I/O using push-pull drivers.
- (2) The extended DAT lines (DAT1-DAT3) are input on power up. They start to operate as DAT lines after SET\_BUS\_WIDTH command. The Host shall keep its own DAT1-DAT3 lines in input mode as well while they are not used. It is defined so in order to keep compatibility to MultiMedia Cards.
- (3) At power up, this line has a 50KOhm pull up enabled in the card. This resistor serves two functions: Card detection and Mode Selection. For Mode Selection, the host can drive the line high or let it be pulled high to select SD mode. If the host wants to select SPI mode, it should drive the line low. For Card detection, the host detects that the line is pulled high. This pull-up should be disconnected by the user during regular data transfer with SET\_CLR\_CARD\_DETECT (ACMD42) command.

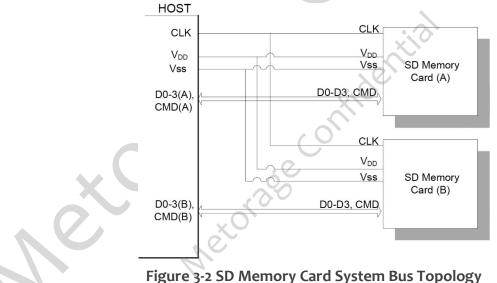
#### 3.2. SD Card Bus Topology

The SD card supports 2 alternative communication protocols, SD and SPI BUS mode. Host can choose either one of both bus mode, same data can be read or written by both modes. SD mode allows 4-bits data transfer way, it provides high performance. SPI mode supports 1-bit data transfer and of course the performance is lower compared to SD mode.

#### 3.3. SD Bus Mode Protocol

In default speed, the SD Memory Card bus has a single master (application); multiple slaves (Cards), synchronous star topology (refer to Figure 3-2). In high speed and UHS-I, the SD Memory Card bus has a single master (application) and single slave (card), synchronous point to point topology. Clock, power and ground signals are common to all cards. Command (CMD) and data (DATO-DAT3) signals are dedicated to each card providing continues point to point connection to all the cards. During initialization process commands are sent to each card individually, allowing the application to detect the cards and assign logical addresses to the physical slots. Data is always sent (received) to (from) each card individually. However, in order to simply the handling of the card stack, after the initialization process, all commands may be sent concurrently to all cards. Addressing information is provided in the command packet.

SD bus allows dynamic configuration of the number of data lines. After power up, by default, the SD Memory Card will use only DATo for data transfer. After initialization the host can change the bus width (number of data active lines). This feature allows easy tradeoff between HW cost and system performance. Note that while DAT1 to DAT3 are not in use, the related Host's DAT lines should be in tristate (input mode). For SDIO cards DAT1 and DAT2 are used for signaling.



The SD bus includes the following signals:

CLK: Host to card clock signal

CMD: Bidirectional Command/Response signal

DATo-DAT3: 4 Bidirectional data signals

 $V_{\text{DD}}, V_{\text{ss1}}, V_{\text{ss2}}$ : Power and ground signals

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						ode Co						
Card	0	1	2	3	4	5	6	7	8	9	10	11
Command		Comma	Block	Reserve	Block		Write	Lock	Applica	I/O		Extensio
Class (CCC)	Basic	nd	read	d	write	Erase	protecti	card	tion	mode	Switch	n
		Queue	Teau	u	write		on	Caru	specific	mode		
CMDo	+											
CMD2	+											
CMD3	+											
CMD4	+											
CMD5										+		
CMD6											+	
CMD7	+											
CMD8	+											
CMD9	+											
CMD10	+											
CMD11	+											
CMD12	+											
CMD13	+											
CMD15	+											
CMD16			+		+			+				
CMD17			+									
CMD18			+									
CMD19			+									
CMD20			+		+							
CMD21												+
CMD23			+		+							
CMD24				$\bigcirc$	+							
CMD25					+							
CMD27					+							
CMD28							+					
CMD29							+					
CMD30							+					
CMD32						+						
CMD33						+						
CMD34-37											+	
CMD38						+						
CMD40								+				
CMD42								+				
CMD43-47		+										
CMD48												+
CMD49												+
CMD50											+	
CMD52										+		
CMD53										+		

#### Table 3-2 SD Mode Command Set

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	0	1	2	3	4	5	6	7	8	9	10	11	
Card Command Class (CCC)	Basic	Comma nd Queue	Block read	Reserve d	Block write	Erase	Write protecti on		Applica tion specific	I/O mode	Switch	Extensi on	
CMD55									+				
CMD56									+				
CMD57											+		
CMD58												+	
CMD59												+	
ACMD6									+			5	
ACMD13									+				
ACMD14									+				
ACMD15									+				
ACMD16									+				
ACMD22									+				
ACMD23									+				
ACMD28									+				
ACMD41									+				
ACMD42									+				
ACMD51									+				
								,					

Commands	Support requirements
CMDo	Mandatory
CMD2	Mandatory
CMD3	Mandatory
CMD4	Mandatory
CMD5	No Support
CMD6	Mandatory for cards version 1.10 and after
CMD7	Mandatory
CMD8	Mandatory for cards version 2.00 and after
CMD9	Mandatory
CMD10	Mandatory
CMD11	Mandatory for cards supporting UHS-I. Optional for cards that do not support UHS-I.
CMD12	Mandatory
CMD13	Mandatory
CMD15	Mandatory
CMD16	Mandatory
CMD17	Mandatory
CMD18	Mandatory
CMD19	Mandatory for cards supporting UHS-I. Optional for cards that do not support UHS-I.

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Commands	Support requirements
	Not support for SDSC cards.
	Mandatory for SDHC and SDXC cards that support Video Speed Class.
CMD20	Optional for SDHC cards that support:
	a) Speed Class; b) UHS Speed Grade,and do not support Video Speed Class.
	Mandatory for SDXC cards that support Speed Class or UHS Speed Grade.
CMD21	Optional
_	Not support for SDSC cards.
CMD23	Mandatory for SDHC and SDXC cards that support UHS104.
cinolog	Optional for SDHC cards and SDXC cards that do not support UHS104.
CMD24	Mandatory for writable type of cards
CMD25	Mandatory for writable type of cards
CMD27	Mandatory for writable type of cards
CMD28	Optional
CMD29	Optional
CMD30	Optional
CMD32	Mandatory for writable type of cards
CMD33	Mandatory for writable type of cards
CMD34-37	Optional for cards version 1.10 and after
0.11-9197	
CMD38	Mandatory for writable type of cards
-	Discard and FULE support is optional
CMD40	Optional
	Optional for cards version 1.01 and 1.10.
CMD42	Mandatory for cards version 2.00 and after.
	COP support is optional for CMD42
CMD43-47	Mandatory for cards supporting Command Queue
-	Optimul
CMD48	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2)
	Manuatory for callos supporting Performance Enhancement functions (refer to 5.0.2)
CMD49	Optional
	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2)
CMD50	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after
CMD50 CMD52	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional
CMD50 CMD52 CMD53	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Optional
CMD50 CMD52 CMD53 CMD55	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Optional Mandatory
CMD50 CMD52 CMD53 CMD55 CMD56	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Optional Mandatory Mandatory
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Optional Mandatory Mandatory Optional for cards version 1.10 and after
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Optional
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59 ACMD6	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Mandatory
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59 ACMD6 ACMD13	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Optional Mandatory Mandatory Mandatory
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59 ACMD6 ACMD13 ACMD14	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Optional Mandatory Mandatory Mandatory Optional
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59 ACMD6 ACMD13 ACMD14 ACMD15	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Optional Mandatory Mandatory Mandatory Optional Optional Optional
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59 ACMD6 ACMD13 ACMD14 ACMD15 ACMD16	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Mandatory Mandatory Mandatory Optional Optional Optional Optional Optional Optional
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59 ACMD6 ACMD13 ACMD13 ACMD14 ACMD15 ACMD16 ACMD22	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Mandatory Mandatory Mandatory Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59 ACMD6 ACMD13 ACMD14 ACMD15 ACMD15 ACMD16 ACMD22 ACMD23	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Mandatory Mandatory Mandatory Optional Optional Optional Optional Optional Optional Optional Optional Optional Mandatory for writable types of cards
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59 ACMD6 ACMD13 ACMD14 ACMD15 ACMD15 ACMD16 ACMD22 ACMD23 ACMD28	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Optional Mandatory Mandatory Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional Optional
CMD50 CMD52 CMD53 CMD55 CMD56 CMD57 CMD58 CMD59 ACMD6 ACMD13 ACMD14 ACMD15 ACMD15 ACMD16 ACMD22 ACMD23	Optional Mandatory for cards supporting Performance Enhancement functions (refer to 5.8.2) Optional for cards version 1.10 and after Optional Mandatory Mandatory Optional for cards version 1.10 and after Optional Optional Mandatory Mandatory Mandatory Optional Optional Optional Optional Optional Optional Optional Optional Optional Mandatory for writable types of cards

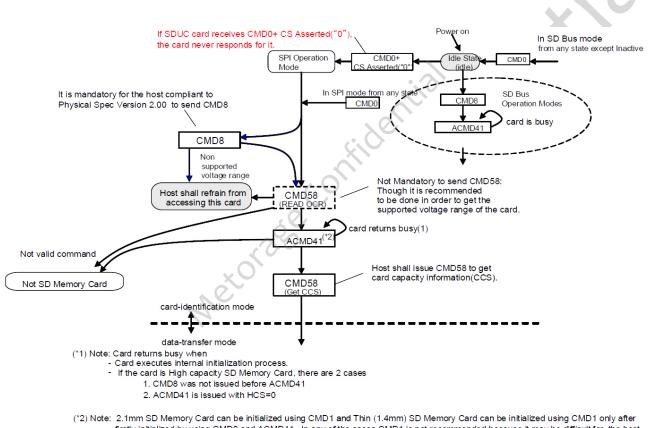
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#### 3.4. SPI Bus Mode Protocol

While the SD Memory Card channel is based on command and data bit streams that are initiated by a start bit and terminated by a stop bit, the SPI channel by byte oriented. Every command or data block is built for 8-bit bytes and is byte aligned with the CS signal (i.e. the length is a multiple of 8 clock cycles). The card starts to count SPI bus clock cycle at the assertion of the CS signal. Every command or data token shall be aligned with 8-clock cycle boundary.

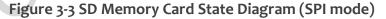
Similar to the SD Memory Card Protocol, the SPI messages consist of command, response and datablock tokens.

The advantage of SPI mode is reducing the host design effort, especially for MMC host side, it just be modified by little change. Note: please use SD card specification to implement SPI mode function, not use MMC specification. For example, SPI mode is initialized by ACMD41, and the registers are different from MMC card, especially CSD register.



) Note: 2.1mm SD Memory Card can be initialized using CMD1 and Thin (1.4mm) SD Memory Card can be initialized using CMD1 only after firstly initialized by using CMD0 and ACMD41. In any of the cases CMD1 is not recommended because it may be difficult for the host to distinguish between MultiMediaCard and SD Memory Card.

If the SD card is initialized by CMD1 and the host treat it as MMC card, not SD card, the Data of the card may be damaged because of wrong interpretation of CSD and CID registers.



Card Comman	nd Class (CCC)	0	1	2	3	4	5	6	7	8	9	10	11
Supported commands	Class description	Basic	Reser ved	Block read	Reser ved	Block write	Erase	Write prote ction	Lock	Applic ation specif ic	I/O mode		Reserv ed
CMDo	Mandatory	+											
CMD1	Mandatory	+											

#### Table 3-3 SPI Mode Command Set

CMD5	Optional										+		
CMD6 <sup>2</sup>	Mandatory											+	
CMD8 <sup>3</sup>	Mandatory	+											
CMD9	Mandatory	+											
CMD10	Mandatory	+											
CMD12	Mandatory	+											
CMD13	Mandatory	+											
CMD16	Mandatory			+		+			+				
CMD17	Mandatory			+									
CMD18	Mandatory			+									
CMD24	Mandatory1					+					-		
CMD25	Mandatory1					+							
CMD27	Mandatory1					+							
CMD28	Optional							+					
CMD29	Optional							+					
CMD30	Optional							+					
CMD32	Mandatory1						+						
CMD33	Mandatory1						+	X					
CMD34-37 <sup>2</sup>	Optional											+	
CMD38	Mandatory1						+						
CMD42 <sup>4</sup>	(Note4)								+				
CMD50 <sup>2</sup>	Optional											+	
CMD52	Optional										+		
CMD53	Optional										+		
CMD55	Mandatory1			$\square$	þ.					+			
CMD56	Mandatory1			V						+			
CMD57 <sup>2</sup>	Optional											+	
CMD58	Mandatory	+	Y										
CMD59	Mandatory	+											
ACMD13	Mandatory									+			
ACMD22	Mandatory1									+			
ACMD23	Mandatory1									+			
ACMD41	Mandatory									+			
ACMD42	Mandatory1									+			
ACMD51	Mandatory1									+			

Note(1):The commands related write and erase are mandatory for the Writable types of Cards.

Note(2):This command was defined in spec version 1.10.

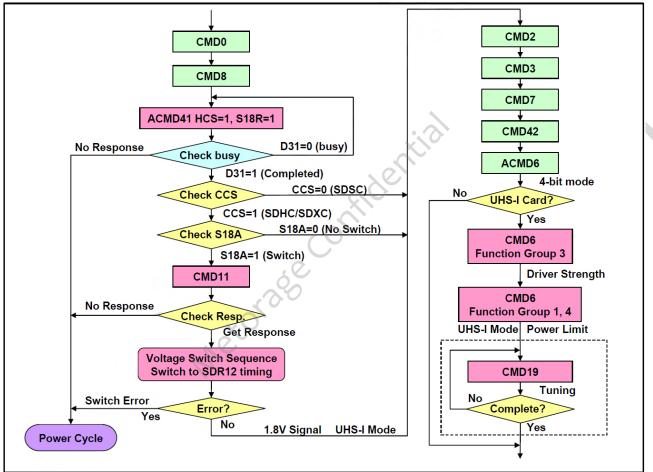
Note(3):This command is newly defined in version 2.00.

Note(4):This command is optional in Version 1.01 and 1.10 and mandatory from Version 2.00. COP support is optional for CMD42.

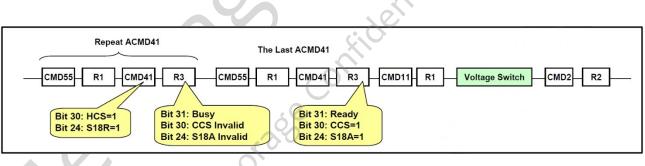
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#### 3.5. SD card initialization

Figure 3-4 presents the initialization flow chart for UHS-I hosts and Figure 3-5 shows sequence of commands to perform voltage switch.







### Figure 3-5 ACMD41 Timing Followed by Voltage Switch Sequence

When signaling level is 3.3V, host repeats to issue ACMD41 with HCS=1 and S18R=1 until the response indicates ready. The argument (HCS and S18R) of the first ACMD41 is effective but the all following ACMD41 should be issued with the same argument.

If Bit31 indicates ready, host needs to check CCS and S18A.

The card indicates S18A=0, which means that voltage switch is not allowed and the host needs to use current signaling level.

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Current Signaling Level	S18R	S18A	Comment
	0	0	1.8V signaling is not requested
3.3V	1	0	The card does not support 1.8V signaling
	1	1	Start signal voltage switch sequence
1.8V	Х	0	Already switched to 1.8V

#### Table 3-4 S18R and S18A Combinations

To change signaling level at the same time between host and card, signal voltage switch sequence is invoked by CMD11 as shown in Figure 3-6. CMD11 is issued only when S18A=1 in the response of ACMD41.

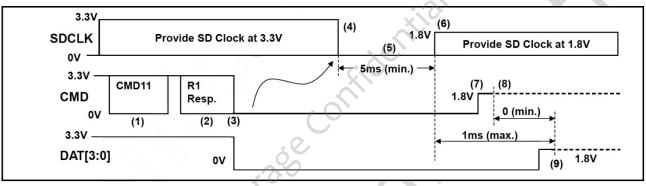


Figure 3-6 Signal Voltage Switch Sequence

# 4. ENVIRONMENTAL SPECIFICATIONS

### 4.1. Environmental Conditions

#### Temperature and Humidity

- Temperature Range (Ta = Temperature ambience)
  - Operational: -25°C ~+ 85°C
  - Storage: -40°C ~ +85°C
- Humidity
  - Operational: RH = 95% under 25°C

#### Shock

#### Table 4-1 Shock Specification

<b>SD card</b> 500G 0.5ms	

Result: No any abnormality is detected when power on.

### Vibration

#### Table 4-2 Vibration Specification

	Condi	- Vibration Orientation	
	Frequency/Displacement	Frequency/Acceleration	vibration Orientation
SD card	20Hz~80Hz/1.52mm	80Hz~2000Hz/20G	Direction: X, Y, Z axis Duration: 30min/direction

Result: No any abnormality is detected when power on.



### **MIFFXXXCY3AQ**

### Drop

\_\_\_\_\_

Эгор	Table 4-3 Drop Specification	n
	Height of Drop	Number of Drops
SD card	150cm free fall	Direction: 6 face; 1 time/face
Result: No any abnormality is d	etected when power on.	
Bending		
	Table 4-4 Bending Specificati	
	Force	Action
SD card	≥ 10N	Hold for 1min; total 5 times.
Result: No any abnormality is d	etected when power on.	
Torque		
	Table 4-5 Torque Specification	on
	Force	Action
SD card	0.15N-m or ±2.5 deg	Hold 30 second/direction Total 5 cycles
Result: No any abnormality is d	etected when power on.	
Durability Mating Cycle Test		>
	Table 4-6 Mating Cycle Test Speci	fication
		Number of Mating Cycle
SD card		10,000 cycles
Result: No any abnormality is d	etected when power on.	
Test Procedure: Refer to sectio	n 4.1.5.1 of Standard Size SD Card I	Mechanical Addendum.
Electrostatic Discharge (ESD)		
	Table 4-7 ESD Specification	1
	Со	ndition Result
Non-op		4KV; 5 times/Pin PASS 5 times/Position PASS
SD card Oper	rating Air: ±8KV; 10 (EN5502	o times/Position B grade, PASS 24-61000-4-2)
Result: No any abnormality is d	etected when power on.	

# 5. SD CARD COMPARISON

-			
	SDHC	SDXC	
File System	FAT32	exFAT	
Addressing Mode	Block (512 byte unit)	Block (512 byte unit)	
HCS/CCS bits of ACMD41	Support	Support	
CMD8 (SEND_IF_COND)	Support	Support	
CMD16 (SET_BLOCKLEN)	Support (Only CMD42)	Support (Only CMD42)	
Partial Read	Not Support	Not Support	
Lock/Unlock Function	Mandatory	Mandatory	
Write Protect Groups	Not Support	Not Support	
Supply Voltage 2.7v – 3.6v (for operation)	Support	2.7v-3.6v	
Total Bus Capacitance for each signal line	40pF	40pF	
CSD Version (CSD_STRUCTURE Value)	20(0x1)		
Speed Class	Mandatory (Class 2 / 4 / 6 / 10)	Mandatory (Class 2 / 4 / 6 / 10)	

#### Table 5-1 Comparing SDHC, and SDXC

Table 5-2 Comparing UHS Speed Grade Symbols

	U1 ( UHS Speed Grade 1)	U3 ( UHS Speed Grade 3)			
Operable Under	UHS-I Bus I/F, UHS-II Bus I/F				
SD Memory Card	SDHC UHS-I and UHS-II, SDXC UHS-I and UHS-II				
Mark		3			
Performance	10 MB/s minimum write speed Under the UHS Class speed condition	30 MB/s minimum write speed Under the UHS Class speed condition			
Applications	Full higher potential of recording realtime broadcasts and capturing large-size HD videos.	Capable of recording 4K2K video.			

\*UHS (Ultra High Speed), the fastest performance category available today, defines bus-interface speeds up to 312 Megabytes per second for greater device performance. It is available on SDXC and SDHC memory cards and devices.

# 6. ELECTRICAL SPECIFICATIONS

### 6.1. Power Consumption

The table below is the power consumption of SD card with different flash memory types.

Table	Table 6-1 Power Consumption of SD card								
	Max. Power	Max.	Max. Read						

Flash Mode		Max. Power Up Current (uA)	Max. Standby Current (uA)	Max. Read Current (mA)	Max. Write Current (mA)	
Default Speed Mode		250	1000	150 @ 3.6V	150 @ 3.6V	
High Speed Mode		250	1000	200 @ 3.6V	200 @ 3.6V	
UHS-I	UHS50/DDR50	250	1000	400 @ 3.6V	400 @ 3.6V	
Mode	UHS104/ DDR50	250	1000	400 @ 3.6V	400 @ 3.6V	

NOTES:

1. Power consumptions are measured at room temperature.

### 6.2. Working Rating

Tabla	6-7	Working	Pating	of	SD	card	
lable	0-2	<b>VVOLKING</b>	naung	OI.	עכ	Cal u	

Item	Symbol	Parameter	Min	Max	Unit
1	Ta	Operating Temperature	-25	+85	°C
2	T <sub>st</sub>	Storage Temperature	-40	+85	°C
3	V <sub>DD</sub>	Voltage	2.7	3.6	V

### 6.3. DC Characteristic

### 6.3.1. Bus Operation Conditions for 3.3V Signaling

### Table 6-3 Threshold Level for High Voltage Range

Parameter	Symbol	Min	Max	Unit	Condition
Supply Voltage	V <sub>DD</sub>	2.7	3.6	V	-
Output High Voltage	V <sub>OH</sub>	0.75*V <sub>DD</sub>	-	V	$I_{OH}$ =-2mA $V_{DD}$ Min
Output Low Voltage	V <sub>OL</sub>		0.125*V <sub>DD</sub>	V	$IOL=2mAV_{DD}Min$
Input High Voltage	V <sub>IH</sub>	0.625*V <sub>DD</sub>	V <sub>DD</sub> +0.3	V	-
Input Low Voltage	VIL	V <sub>ss</sub> -0.3	0.25*V <sub>DD</sub>	V	-
Power Up Time	-	-	250	ms	From oV to $V_{\text{DD}}$ min

#### Table 6-4 Peak Voltage and Leakage Current

	=	0	0			
Parameter	Symbol	Min	Max	Unit	Remarks	
Peak voltage on all lines	-	-0.3	V <sub>DD</sub> +0.3	V	-	
All Inputs						
Input Leakage Current	-	-10	10	uA	-	
All Outputs						
Output Leakage Current	-	-10	10	uA	-	

### **MIFFXXXCY3AQ**

Parameter	Symbol	Min	Max	Unit	Condition
Supply Voltage	$V_{\text{DD}}$	2.7	3.6	V	-
Regulator Voltage	V <sub>DDIO</sub>	1.7	1.95	V	Generated by $V_{\mbox{\tiny DD}}$
Output High Voltage	V <sub>OH</sub>	1.4	-	V	I <sub>OH</sub> =-2mA
Output Low Voltage	V <sub>OL</sub>	-	0.45	V	I <sub>OL</sub> =2mA
Input High Voltage	$V_{\mathtt{IH}}$	1.27	2.00	V	
Input Low Voltage	$V_{\text{IL}}$	V <sub>ss</sub> -0.3	0.58	V	

#### Table 6-5 Threshold Level for 1.8V Signaling

Table 6-6 Input Leakage Current for 1.8V Signaling

		-			
Parameter	Symbol	Min	Max	Unit	Remarks
Input Leskage Current	_	-2	2	uA	DAT3 pull-up is
Input Leakage Current	-	- 2	2		disconnected.

### 6.3.2. Bus Signal Line Load

#### Bus Operation Conditions – Signal Line's Load

Total Bus Capacitance = C<sub>HOST</sub> + C<sub>BUS</sub> + N C<sub>CARD</sub>

# Table 6-7 Bus Signal Line Load of SD Card

Parameter	Symbol	Min	Max	Unit	Remark
Pull-up resistance	R <sub>cmd</sub> R <sub>dat</sub>	10	100	kΩ	to prevent bus floating
Total bus capacitance for each signal line	CL	-	40	pF	1 card C <sub>HOST</sub> +C <sub>BUS</sub> shall not exceed 30 pF
Card Capacitance for each signal pin	CCARD	-	10	рF	-
Maximum signal line inductance	-	-	16	nH	-
Pull-up resistance inside card (pin1)	R <sub>DAT3</sub>	10	90	kΩ	May be used for card detection
Capacity Connected to Power Line	Cc	-	5	uF	To prevent inrush current

### **MIFFXXXCY3AQ**

#### 6.3.3. Power Up Time of Host

The host needs to keep power line level less than 0.5V and more than 1ms before power ramp up.

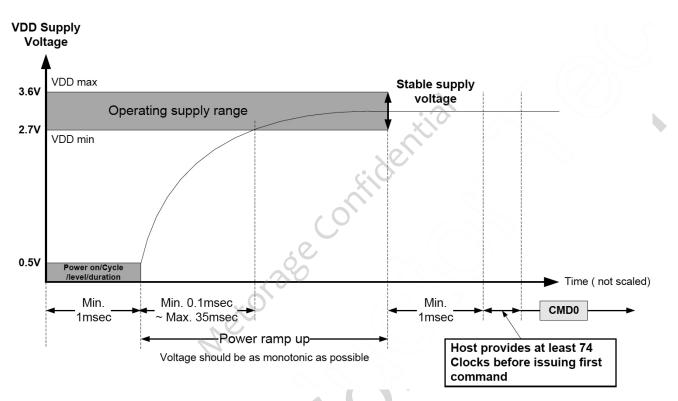


Figure 6-1 Power Up Diagram of Host

#### Power On or Power Cycle

Followings are requirements for Power on and Power cycle to assure a reliable SD Card hard reset.

- (1) Voltage level shall be below 0.5V.
- (2) Duration shall be at least 1ms.

#### Power Supply Ramp Up

The power ramp up time is defined from 0.5V threshold level up to the operating supply voltage which is stable between VDD (min.) and VDD (max.) and host can supply SDCLK. Followings are recommendations of Power ramp up:

(1) The voltage of power ramp up should be monotonic as much as possible.

- (2) The minimum ramp up time should be 0.1ms.
- (3) The maximum ramp up time should be 35ms for 2.7-3.6V power supply.
- (4) Host shall wait until VDD is stable.
- (5) After 1ms VDD stable time, the host provides at least 74 clocks before issuing the first command.

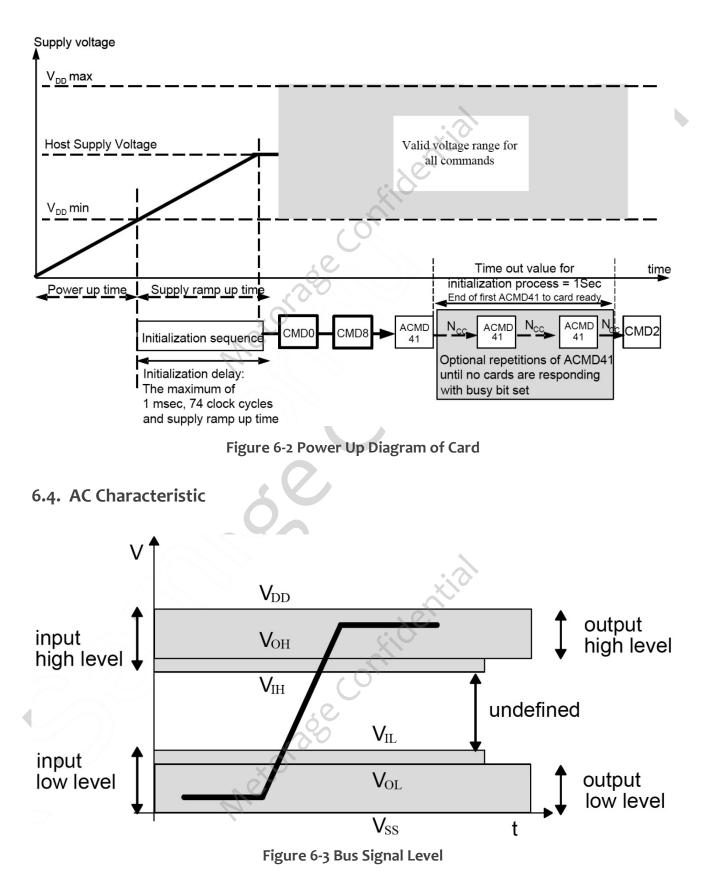
#### Power Down and Power Cycle

- (1) When the host shuts down the power, the card VDD shall be lowered to less than 0.5Volt for a minimum period of 1ms. During power down, DAT, CMD, and CLK should be disconnected or driven to logical o by the host to avoid a situation that the operating current is drawn through the signal lines.
- (2) If the host needs to change the operating voltage, a power cycle is required. Power cycle means the power is turned off and supplied again. A power cycle is also needed for accessing cards that are already in *Inactive State.* To create a power cycle the host shall follow the power down description before power up the card (i.e. the card V<sub>DD</sub> shall be once lowered to less than 0.5Volt for a minimum period of 1ms).

## **MIFFXXXCY3AQ**

#### 6.3.4. Power Up Time of Card

A device shall be ready to accept the first command within 1ms from detecting VDD min. The device may use up to 74 clocks for preparation before receiving the first command.



### **MIFFXXXCY3AQ**

6.4.1. SD Interface Timing (Default)

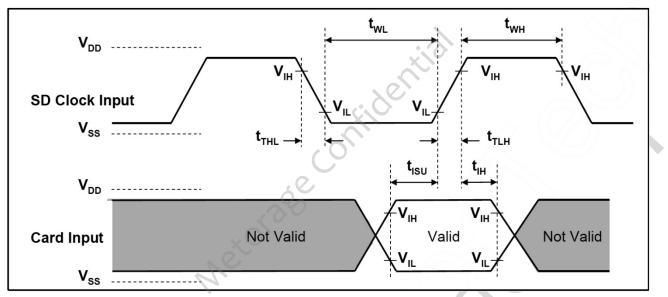


Figure 6-4 Card Input Timing (Default Speed Card)

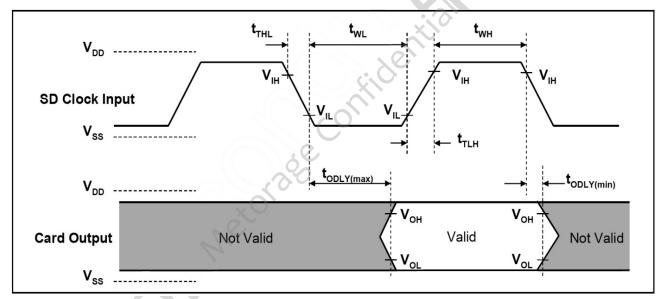


Figure 6-5 Card Output Timing (Default Speed Card)

Table 0-0 bus finning – Parameters values (Default Speed)									
Parameter	Symbol	Min	Max	Unit	Remark				
Clock CLK (All va	lues are refe	rred to min	(V <sub>IH</sub> ) and ma	ax(V <sub>IL</sub> )					
Clock frequency Data Transfer Mode	f <sub>PP</sub>	0	25	MHz	C <sub>card</sub> ≤ 10 pF (1 card)				
Clock frequency Identification Mode	f <sub>op</sub>	0(1)/100	400	kHz	C <sub>card</sub> ≤ 10 pF (1 card)				
Clock low time	$t_{\text{WL}}$	10	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)				
Clock high time	$t_{WH}$	10	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)				
Clock rise time	t <sub>TLH</sub>	-	10	ns	C <sub>card</sub> ≤ 10 pF (1 card)				

#### Table 6-8 Bus Timing – Parameters Values (Default Speed)

### **MIFFXXXCY3AQ**

Clock fall time	$t_{\text{THL}}$	-	10	ns	C <sub>card</sub> ≤ 10 pF (1 card)	
Inputs	CMD, DAT (I	referenced t	to CLK)			
Input set-up time	t <sub>ISU</sub>	5	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)	
Input hold time	$t_{\text{IH}}$	5	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)	
Outputs CMD, DAT (referenced to CLK)						
Output Delay time during Data Transfer Mode	t <sub>ODLY</sub>	0	14	ns	C∟≤ 40 pF (1 card)	
Output Delay time during Identification Mode	t <sub>ODLY</sub>	0	50	ns	C∟≤ 40 pF (1 card)	

(1) oHz means to stop the clock. The given minimum frequency range is for cases where continuous clock is required.



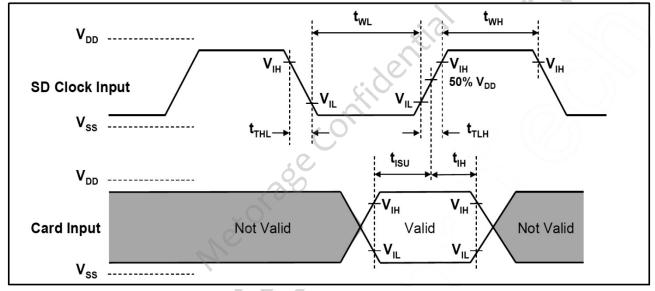


Figure 6-6 Card Input Timing (High Speed Card)

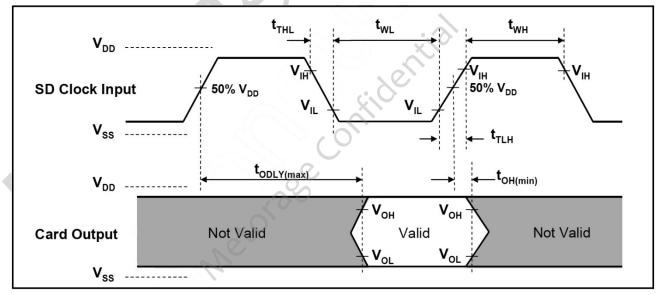


Figure 6-7 Card Output Timing (High Speed Mode)

Table 6-9 Bus Timing – Parameters Values (High Speed)									
Parameter	Symbol	Min	Max	Unit	Remark				
Clock CLK (All va	Clock CLK (All values are referred to $min(V_{IH})$ and $max(V_{IL})$								
Clock frequency Data Transfer Mode	$f_{PP}$	0	50	MHz	C <sub>card</sub> ≤ 10 pF (1 card)				
Clock low time	$t_{WL}$	7	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)				
Clock high time	$t_{WH}$	7	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)				
Clock rise time	$t_{\text{TLH}}$	-	3	ns	C <sub>card</sub> ≤ 10 pF (1 card)				
Clock fall time	$t_{\text{THL}}$	-	3	ns	C <sub>card</sub> ≤ 10 pF (1 card)				
Input	s CMD, DAT	(reference	ed to CLK)						
Input set-up time	$t_{\text{ISU}}$	6	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)				
Input hold time	$t_{\mathtt{IH}}$	2	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)				
Outputs CMD, DAT (referenced to CLK)									
Output Delay time during Data Transfer Mode	t <sub>ODLY</sub>	-	14	ns	C∟ ≤ 40 pF (1 card)				
Output Hold time	Т <sub>он</sub>	2.5	-	ns	C <sub>L</sub> ≤ 15 pF (1 card)				
Total System capacitance of each line <sup>1</sup>	CL		40	рF	CL ≤ 15 pF (1 card)				

Table 6-9	Bus Timing -	- Parameters	Values	(High S	peed)
1 4 2 1 2 2 3			I did CD	\····ə·· -	pecaj

(1) In order to satisfy severe timing, the host shall drive only one card.

## 6.4.3. SD Interface Timing (SDR12, SDR25, SDR50 and SDR104 Modes) Input

$V_{ss} \longrightarrow t_{cR} \longrightarrow t_{cR} \longrightarrow t_{cR}$	V <sub>DDIO</sub> SDCLK Input V <sub>ss</sub>		V <sub>IH</sub> V <sub>CT</sub>
-------------------------------------------------------------------------------	-----------------------------------------------------	--	------------------------------------

Figure 6-8 Clock Signal Timing

Symbol	Min	Max	Unit	Remark
t <sub>CLK</sub>	4.80	-	ns	208MHz (Max.), Between rising edge, $V_{CT}$ = 0.975V
t <sub>CR</sub> , t <sub>CF</sub>	_	0.2* tclk	ns	<pre>tcr, tcr &lt; 0.96ns (max.) at 208MHz, Ccard=10pF tcr, tcr &lt; 2.00ns (max.) at 100MHz, Ccard=10pF The maximum value of tcr, tcr is 10ns regardless of clock frequency</pre>
Clock Duty	30	70	%	-

# Table 6-10 Clock Signal Timing

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### **MIFFXXXCY3AQ**

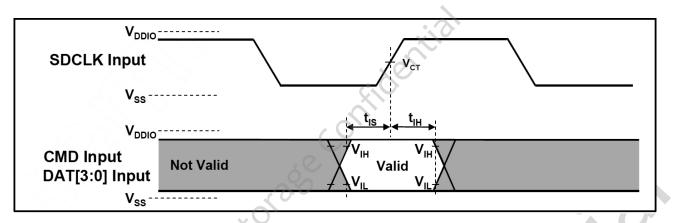
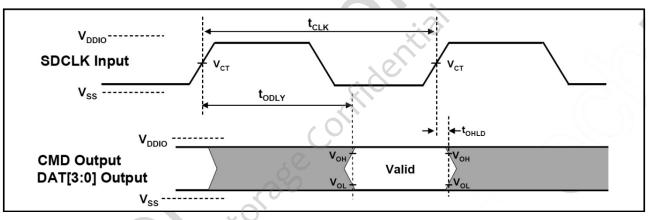


Figure 6-9 Card Input Timing

#### Table 6-11 SDR50 and SDR104 Input Timing

Symbol	Min	Max	Unit	SDR104 Mode
t <sub>IS</sub>	1.40	-	ns	C <sub>CARD</sub> =10pF, V <sub>CT</sub> = 0.975V
t <sub>IH</sub>	0.801	-	ns	$C_{CARD} = 5pF$ , $V_{CT} = 0.975V$
Symbol	Min	Max	Unit	SDR50 Mode
t <sub>IS</sub>	3.00	_	ns	Ccard =10pF, Vct= 0.975V
LIS	5.00		115	

#### Output(SDR12, SDR25, SDR50)



### Figure 6-10 Output Timing of Fixed Data Window

Table 6-12 Output	Timing of Fixed D	ata Window (SDR12,	SDR25, SDR50)

Symbol	Min	Max	Unit	Remark
t <sub>ODLY</sub>		7.5	ns	$t_{CLK}$ >=10.0ns, CL=30pF,using driver Type B, for SDR50
todly		14	ns	$t_{\text{CLK}}\xspace=20.0ns$ , $C_{\text{L}}\xspace=40pF$ , using driver Type B, for SDR25 and SDR12
Тон	1.5	-	ns	Hold time at the todly (min.), CL=15pF

### **MIFFXXXCY3AQ**

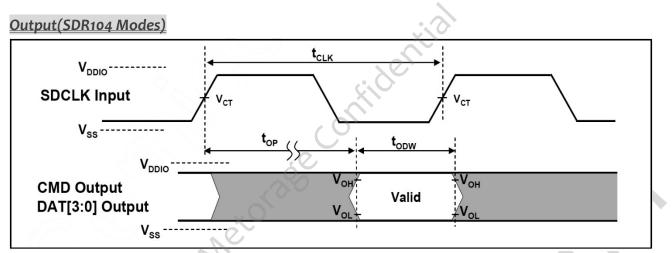


Figure 6-11 Output Timing of Variable Data Window

Table 6-12	<b>Output Timing</b>	of Variable	Data Window	$(SDR_{104})$
Table 0-13	Output mining			(301104)

Symbol	Min	Max	Unit	Remark
top	0	2	Ul	Card Output Phase
∆t <sub>op</sub>	-350	+1550	ps	Delay variable due to temperature change after tuning
t <sub>odw</sub>	0.60	-	Ul	$t_{ODW}$ = 2.88ns at 208MHz

# 6.4.4. SD Interface Timing (DDR50 Mode)

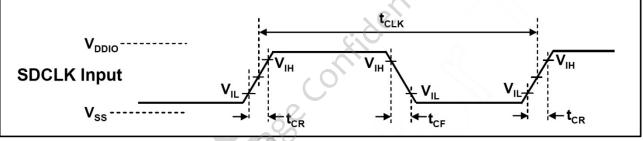


Figure 6-12 Clock Signal Timing

# Table 6-14 Clock Signal Timing

Symbol	Min	Max	Unit	Remark		
t <sub>clк</sub>	20	-	ns	50MHz (Max.), Between rising edge		
t <sub>CR</sub> , t <sub>CF</sub>		0.2* t <sub>CLK</sub>	ns	$t_{CR},\ t_{CF}$ < 4.00ns (max.) at 50MHz, $C_{CARD}{=}10pF$		
Clock Duty	45	55	%	-		

### **MIFFXXXCY3AQ**

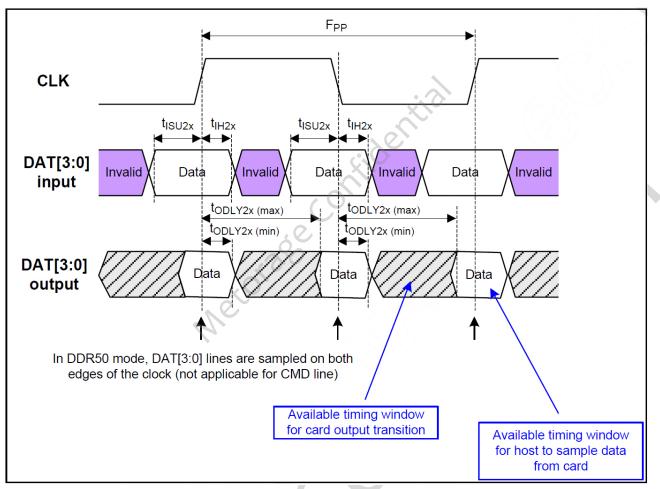


Figure 6-13 Timing Diagram DAT Inputs/Outputs Referenced to CLK in DDR50 Mode

Table 6-15 Bus Timings – Parameters Values (DDR50 Mode)								
Parameter	Symbol	Min	Max	Unit	Remark			
Input CMD (referenced to CLK rising edge)								
Input set-up time	$t_{\text{ISU}}$	3	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)			
Input hold time	t <sub>IH</sub>	0.8	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)			
Output CMD (referenced to CLK rising edge)								
Output Delay time during Data Transfer Mode	t <sub>ODLY</sub>	-	13.7	ns	C∟≤ 30 pF (1 card)			
Output Hold time	Т <sub>он</sub>	1.5	-	ns	C∟≥ 15 pF (1 card)			
Inputs DAT (referenced to CLK rising and falling edges)								
Input set-up time	$t_{\rm ISU2x}$	3	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)			
Input hold time	${\tt t}_{\tt IH2x}$	0.8	-	ns	C <sub>card</sub> ≤ 10 pF (1 card)			
<b>Outputs DAT</b> (referenced to CLK rising and falling edges)								
Output Delay time during Data Transfer Mode	t <sub>ODLY2x</sub>	-	7.0	ns	C∟≤ 25 pF (1 card)			
Output Hold time	T <sub>OH2x</sub>	1.5	-	ns	C∟≥ 15 pF (1 card)			

# 7. HOST SYSTEM DESIGN GUILDELINES

### 7.1. Efficient Data Writing to SD Memory Card

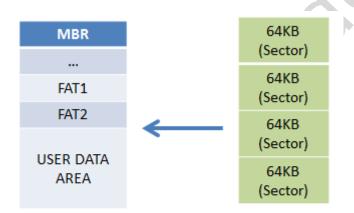
In order to optimize sequential writing performance and WAF (Write Amplification Factor), it is recommended to use allocation unit (AU) writing.

It is recommended that Multiple\_Block\_Write shall be used as a command for writing data, and the size of data written by each command should be the FAT cluster x n (n: integer)

#### 7.1.1. Write\_Single\_Block and Write\_Multiple\_Block

Write single block (CMD24) was written by one sector (512Bytes), which is suitable to write small area such like updating file system area (FAT). Besides, write multiple blocks (CMD25) is a command for writing data to blocks that have sequential address per command, which is suitable to write large area such as user data. Write multiple blocks with a cluster unit (512Byte x 128 Sectors = 64KByte) in the file system is an efficient access to the flash memory, it is obviously to provide higher speed to compared to single write block.

And it could be estimated that SD card internal process would be reduced to save power consumption and flash write amplification factor, that is why the efficient data writing was recommended. To avoid the command issued by 512Bytes with single write block, software processes in the host device become faster. For this operation, check the sectors in the SD card and file system as Figure 7-1



Heading address of user data area shall match with the heading of 64KB boundary of SD logical address.

#### Figure 7-1 Matching between logical address and file system

Note: Large Cluster unit is better for performance and WAF, for example, 128KB, 256KB or 512KB. Large cluster unit also can save write command numbers and few transfer time.

### 7.2. Basic Process of Error Handling

#### 7.2.1. Retry Process

Execute the process by sending commands again, especially for signal issue between card and host.

#### 7.2.2. Recovery Process

Confirm card status is in Transfer State, if card status is not in Transfer State, please issue Stop command to recover it and execute or continue flow. If there was UECC during read/write status, we could use recovery process to recover it.

#### 7.2.3. Tuning Write Command Process

In order to adjust Host CMD and CLK timing, the way is issue tuning command to confirm what the device response and data was received by host. Based on the response, host was adjusting the timing step by step and recording the pass range. Through this flow host could adjust the appropriate timing settings to avoid unexpected handshaking issue.

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### **MIFFXXXCY3AQ**

#### 7.2.4. Tuning Read Command Process

In order to adjust Host CLK and DAT timing, the way is issue tuning command to confirm what the device response and data was received by host. Based on the response, host was adjusting the timing step by step and recording the pass range. Through this flow host could adjust the appropriate timing settings to avoid unexpected handshaking issue.

#### 7.2.5. Exception Handling Process

No doubt that sometimes we would face all error handling above could not recover it successfully, and we could react based on the situation.

- If there was error in response, we could re-initialize the card.
- If it was signal issue, we could set up signal status by reading data and tuning command.

#### 7.3. Common Error Handling in SPI and SD mode

#### 7.3.1. Time-out

Run the Retry Process. No response from CMD, it might be signal or status got problem. To avoid the infinite loop, implement a retry counter in the host so that, if the retry counter expires, the exception handling starts in the host.

#### 7.3.2. Error Detect (CMD CRC Error)

Run the Recovery Process. If it got second time failure with CRC, the setting might be too margin to receive response stably. Suggestion is use tuning write command to fix timing and then retry it.

#### 7.3.3. Error Detect (Other Error) in SPI and SD mode

Run the Recovery Process.

#### 7.3.4. Others

Most errors could be recovered by running the Recovery Process, let card come into Transfer State and then executing the flow we planned. If it does not work, please use exception method to come back initial state.

### 7.4. Data Error Handling in SPI and SD mode

#### 7.4.1. Time-out

Run the Recovery Process. While the state was recovered, run the flow again.

#### 7.4.2. Read CRC16 Error

Run the Recovery Process. If it got second time failure with CRC, the setting might be too margin to receive data stably. Suggestion is use tuning read date to fix timing and then retry it.

#### 7.4.3. Write CRC Status Error

Run the Recovery Process. If it got second time failure with CRC, the setting might be too margin to receive CRC status stably. Suggestion is use tuning read date to fix timing and then retry it.

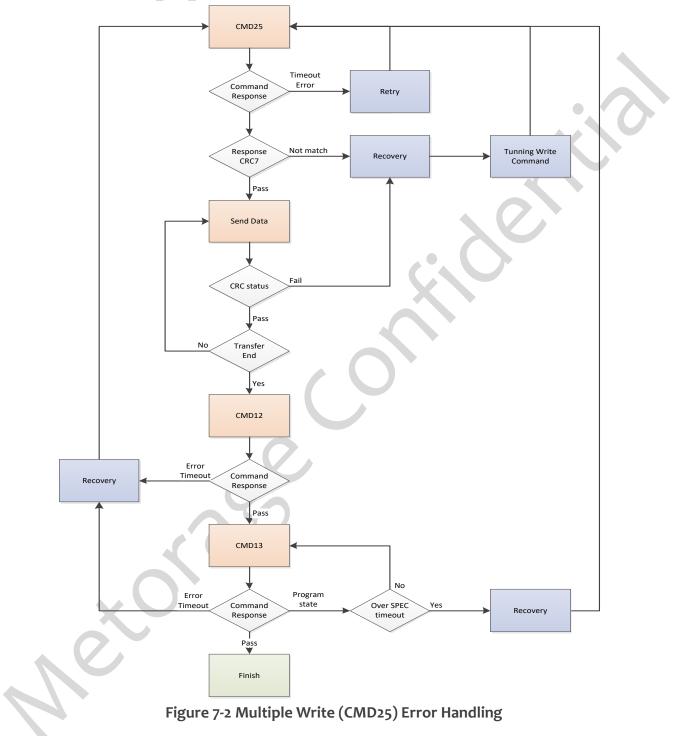
#### 7.4.4. Others

Most errors could be recovered by running the Recovery Process, let card come into Transfer State and then executing the flow we planned.

### **MIFFXXXCY3AQ**

### 7.5. Multiple Block Write (CMD25) Process

- If Response is ADDRESS\_OUT\_OF\_RANGE, please confirm writing address.
- If Response is DEVICE\_IS\_LOCKED, please stop writing data.
- If Response is COM\_CRC\_ERROR, run retry or tuning.



### **MIFFXXXCY3AQ**

### 7.6. Retry Error handling

In order to avoid signal issue caused unexpected response from device, we could use Retry Process to fix it.

- Please make sure card state is in transfer state before issuing following commands.
- To avoid the infinite loop, implement a retry counter in the host.
- If the device could not respond to CMD13 normally, please run exception handling to recover card status.

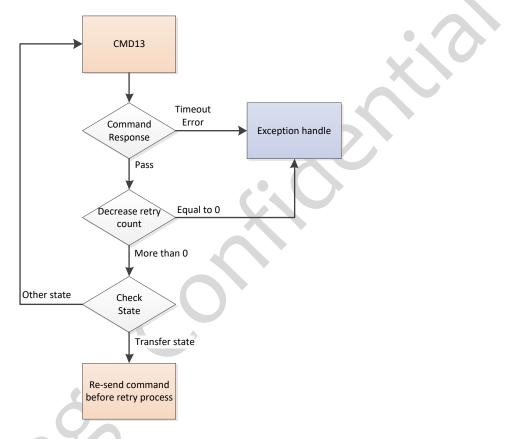


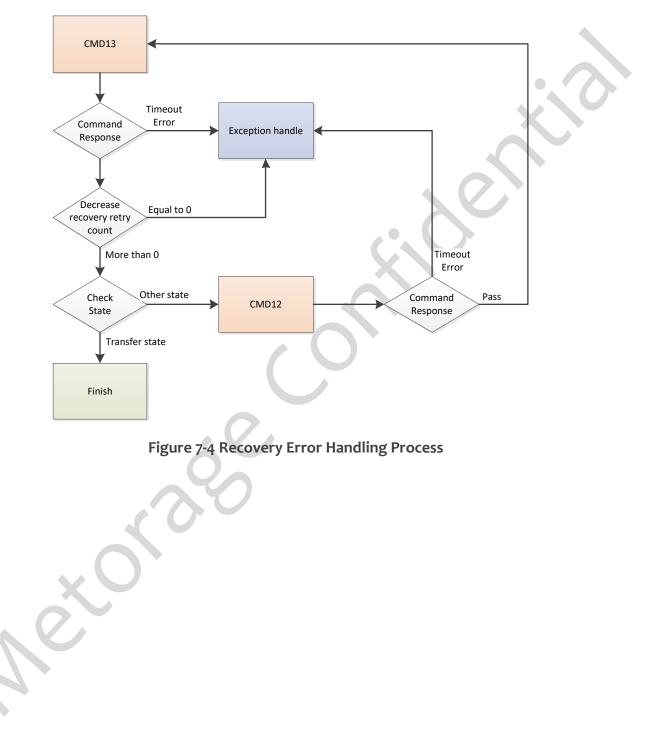
Figure 7-3 Retry Error Handling Process

### **MIFFXXXCY3AQ**

### 7.7. Recovery Error Handling

Sometimes the device failure could not be recovered by Retry Process, it suggests to execute STOP Command (CMD12) to stop whole commands and response and then run following flow.

- Please confirm card status is in Transfer state
- In order to avoid infinite loops, host has to set up a retry counter number.



### **MIFFXXXCY3AQ**

### 7.8. Tuning Write Command Error Handling

Reconfirm the card's pass range, to make sure card could receive host commands.

- If there was no any pass window, it might be connect issue or signal issue
- Pass Range depends on frequency level, higher frequency makes fewer pass range

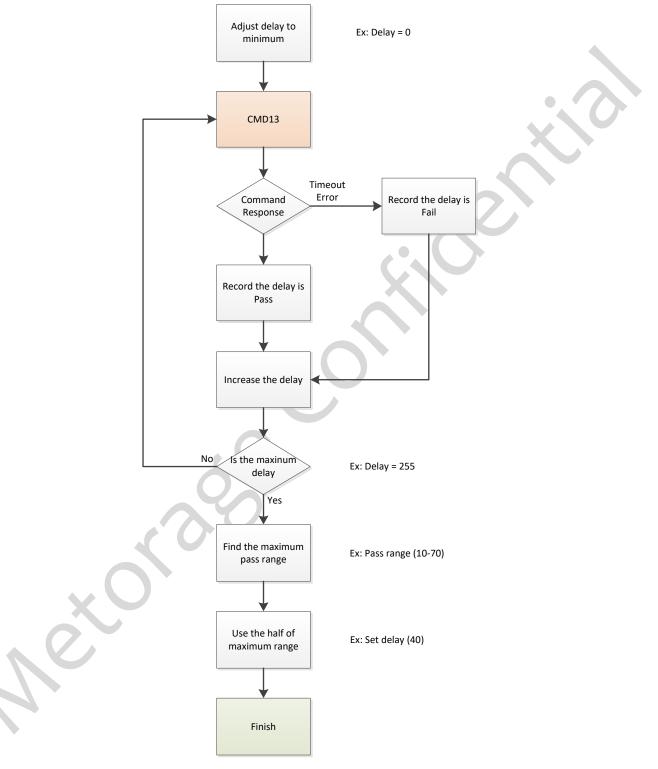


Figure 7-5 Tuning Write Command Error Handling Process

### **MIFFXXXCY3AQ**

### 7.9. Exception Error Handling

- Error in Card's response or data output time-out, it could re-initialize the card.
- If there was CMD CRC7 issue, it could use tuning write command process to find out appropriate timing.
- If there was DAT CRC16 issue, it could use tuning read command process to find out appropriate timing.

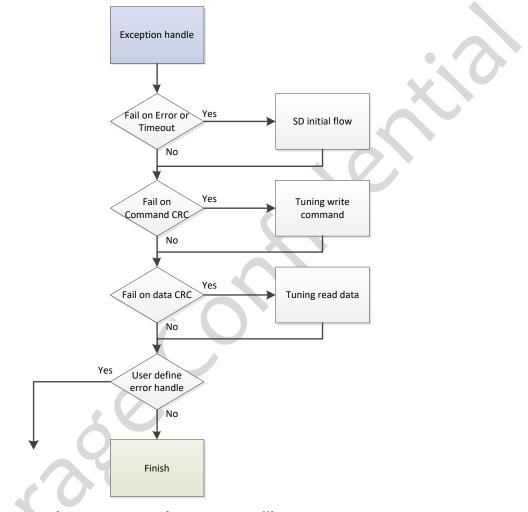


Figure 7-6 Exception Error Handling Process

### **MIFFXXXCY3AQ**

### 7.10. Multiple Blocks Read (CMD18) Error Handling Process

- If card responded ADDRESS\_OUT\_OF\_RANGE, please check reading address
- If card responded DEVICE\_IS\_LOCKED, please stop reading data
- If card responded COM\_CRC\_ERROR, run Retry or Tuning Process

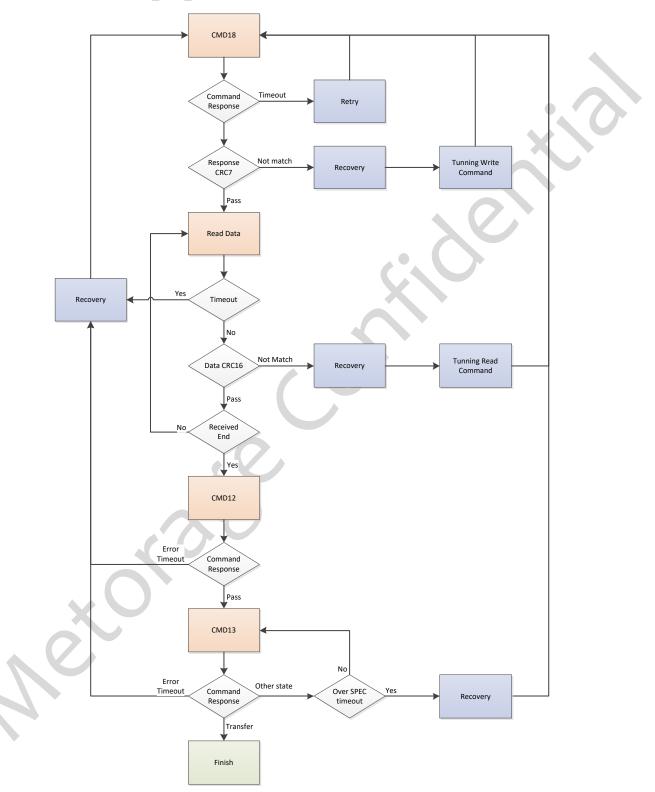


Figure 7-7 Multiple Blocks Read (CMD18) Error Handling Process

### **MIFFXXXCY3AQ**

### 7.11. Tuning Read Data Error Handling

Reconfirm the card's pass range, to make sure host could receive card's Response and Data.

- If there was no any pass window, it might be connect issue or signal issue
- Pass Range depends on frequency level, higher frequency makes fewer pass range

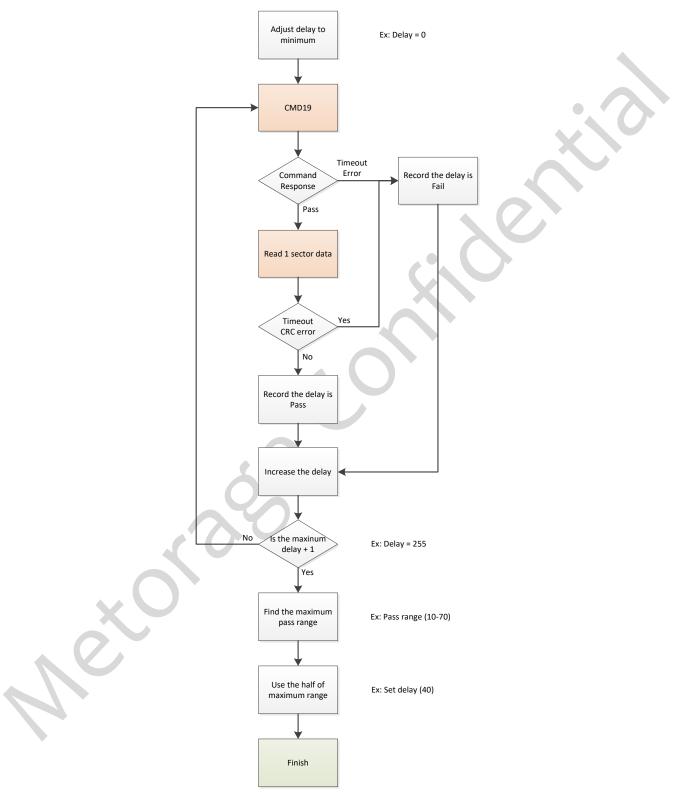


Figure 7-8 Tuning Read Data Error Handling Process

# 8. CARD REGISTERS

### 8.1. Card Identification Register (CID)

The Card Identification (CID) register is 128 bit wide. It contains the card identification information used during the card identification phase. Every individual flash card shall have a unique identification number.

The structure of the CID register is defined in the following table.

CID Bit	Width	Name	Field	Value	
[127:120]	8	Manufacture ID	MID	27h	
[119:104]	16	OEM/Application ID	OID	5048h	
[103:64]	40	Product Name	PNM	4D45544F52h	
[63:56]	8	Product Revision	PRV		
[55:24]	32	Product Serial Number	PSN		
[23:20]	4	Reserved			
[19:8]	12	Manufacturing Date	MDT		
[7:1]	7	CRC7 check sum	CRC		
[0]	1	Not used, always"1			

#### Table 8-1 Card Identification Register (CID) fields

All contents in the CID table are programmable; Manufacturers can update the CID data through utility. Manufacturers should license MID and OID field form the SD Card Association (SDA)

### 8.2. Card Specific Data Register (CSD)

The Card-Specific Data register provides information regarding access to the card contents. The CSD defines the data format, error correction type, maximum data access time, whether the DSR register can be used, etc. The programmable part of the register (entries marked by W or E, see below) can be changed by CMD27. The CSD Table Version 2.0(as shown below) is applied to SDHC and SDXC Cards. Note that bits [15:0] are programmable by the host side. Refer to the SD specification for detailed information.

### **MIFFXXXCY3AQ**

CSD Bit	Width	Name	Field	Value	Note
[127:126]	2	CSD structure	CSD_STRUCTURE	1 h	Ver2.0
[125:120]	6	Reserved			
[119:112]	8	Data read access-time 1	TAAC	0E h	1ms
[111:104]	8	Data read access-time2 in CLK cycles (NSA*100)	NSAC	0 h	
[103:96]	8	Max data transfer rate	TRAN_SPEED	32 h 5A h 0B h 2B h	Default High speed SDR50/DDR50 SDR104
[95:84]	12	Card command classes	ССС	5B5 h	0,2,4,5,7,8,10
[83:80]	4	Max. read data block length	READ_BL_LEN	9 h	512 Byte
[79]	1	Partial block read allowed	READ_BL_PARTIAL	0 h	No
[78]	1	Write block misalignment	WRITE_BLK_MISALIGN	0 h	No
[77]	1	Read block misalignment	READ_BLK_MISALIGN	0 h	No
[76]	1	DSR implemented	DSR_IMP	0 h	No
[75:70]	6	Reserve			
[69:48]	22	Device size	C_SIZE	See Note	00E767h-32GB 01D0BFh-64GB 03A6FFh-128GB
[47]	1	Reserved			
[46]	1	Erase single block enable	ERASE_BLK_EN	1 h	Yes
[45:39]	7	Erase sector size	SECTOR_SIZE	7F h	128
[38:32]	7	Write protect group size	WP_GRP_SIZE	0 h	Not supported
[31]	1	Write protect group enable	WP_GRP_ENABLE	0 h	No
[30:29]	2	Reserved			
[28:26]	3	Write speed factor	R2W_FACTOR	2 h	x4
[25:22]	4	Max. write data block length	WRITE_BL_LEN	9 h	512 Byte
[21]	1	Partial block write allowed	WRITE_BL_PARTIAL	0 h	No
[20:16]	5	Reserved			
[15]	1	File format group	FILE_FORMAT_GRP	0 h	Not use
[14]	1	Copy flag	COPY	0 h	Original
[13]	1	Permanent write protection	PERM_WRITE_PROTECT	0 h	Not Protected
[12]	1	Temporary write protection	TMP_WRITE_PROTECT	0 h	Not Protected
[11:10]	2	File format	FILE_FORMAT	0 h	Not use
[9:8]	2	Reserved			
[7:1]	7	CRC	CRC	CRC7	

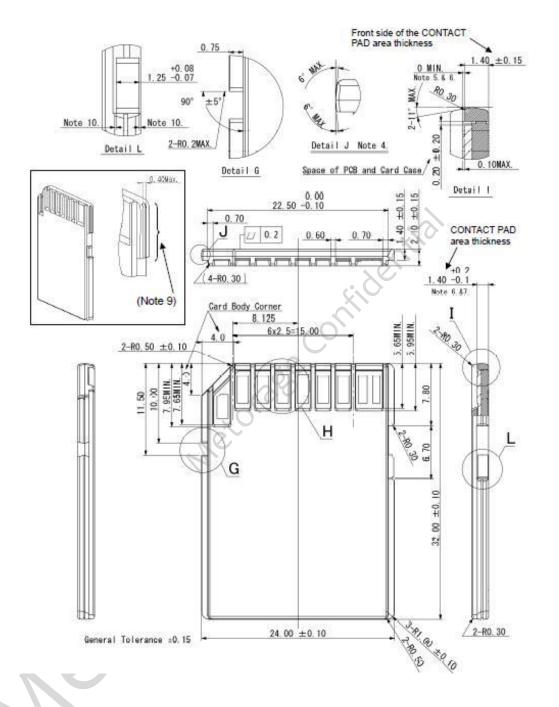
#### Table 8-2 Card Specific Data Register (CSD)





# 9. PHYSICAL DIMENSION

Dimension: 32mm(L) x 24mm(W) x 2.1mm(H)



# **10. APPENDIX**

### 10.1. Endurance characteristic

3,000cycles/block (nominal value: under specified conditions)\*This value is not guaranteed